

N-Channel Power MOSFET

600V, 24A, 165mΩ

FEATURES

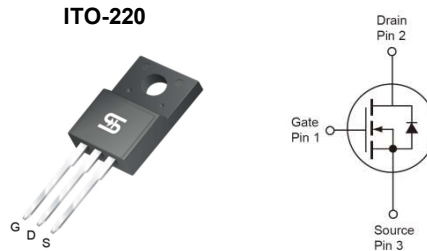
- Super-Junction technology
- High performance, small $R_{DS(ON)} * Q_g$ figure of merit (FOM)
- High ruggedness performance
- 100% UIS & R_g tested
- High commutation performance
- ROHS Compliant
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
V_{DS}	600	V
$R_{DS(on)}$ (max)	165	mΩ
Q_g	44	nC

APPLICATIONS

- Power Supply
- AC/DC LED Lighting



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V_{DS}	600	V	
Gate-Source Voltage	V_{GS}	± 30	V	
Continuous Drain Current ^(Note 1)	I_D	$T_C = 25^\circ\text{C}$	24	A
		$T_C = 100^\circ\text{C}$	15	A
Pulsed Drain Current ^(Note 2)	I_{DM}	72	A	
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	P_D	89	W	
Single Pulse Avalanche Energy ^(Note 3)	E_{AS}	450	mJ	
Single Pulse Avalanche Current ^(Note 3)	I_{AS}	4.2	A	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	$^\circ\text{C}$	

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\theta JC}$	1.4	$^\circ\text{C/W}$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	60	$^\circ\text{C/W}$

Thermal Performance Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static ^(Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 1mA$	BV_{DSS}	600	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1mA$	$V_{GS(TH)}$	3	3.9	5	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I_{DSS}	--	--	100	μA
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 11.3A$	$R_{DS(on)}$	--	150	165	m Ω
Dynamic ^(Note 5)						
Total Gate Charge	$V_{DS} = 300V, I_D = 24A, V_{GS} = 10V$	Q_g	--	44	--	nC
Gate-Source Charge		Q_{GS}	--	13	--	
Gate-Drain Charge		Q_{gd}	--	18	--	
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	C_{iss}	--	1900	--	pF
Output Capacitance		C_{oss}	--	1523	--	
Reverse Transfer Capacitance		C_{rss}	--	68	--	
Gate Resistance	$f = 1.0MHz$	R_g	--	1.6	3.2	Ω
Switching ^(Note 6)						
Turn-On Delay Time	$V_{DD} = 300V, R_G = 10\Omega, I_D = 15A, V_{GS} = 10V$	$t_{d(on)}$	--	30	--	ns
Turn-On Rise Time		t_r	--	50	--	
Turn-Off Delay Time		$t_{d(off)}$	--	60	--	
Turn-Off Fall Time		t_f	--	12	--	
Source-Drain Diode ^(Note 4)						
Body-Diode Continuous Forward Current		I_S	--	--	20	A
Body-Diode Pulsed Current		I_{SM}	--	--	60	A
Forward Voltage	$I_S = 20A, V_{GS} = 0V$	V_{SD}	--	0.9	1.4	V
Reverse Recovery Time	$I_S = 20A$	t_{rr}	--	410	--	ns
Reverse Recovery Charge						

Notes:

1. Current limited by package.
2. Pulse width limited by the maximum junction temperature.
3. $L = 50mH, I_{AS} = 4.2A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
4. Pulse test: $PW \leq 300\mu s$, duty cycle $\leq 2\%$.
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

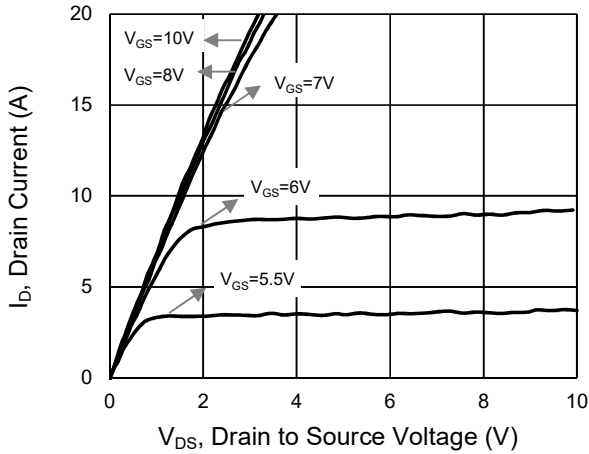
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM60NC165CI C0G	ITO-220	50pcs / Tube

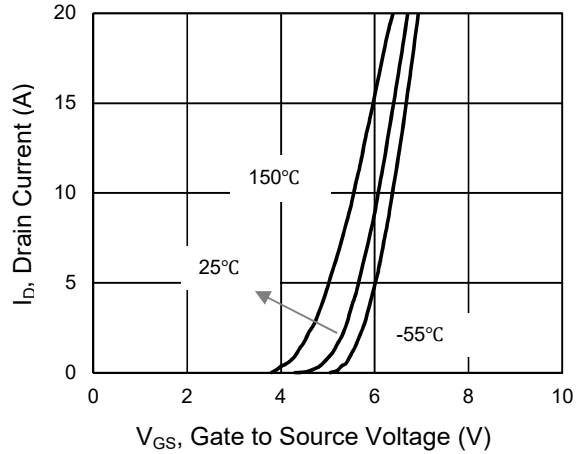
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

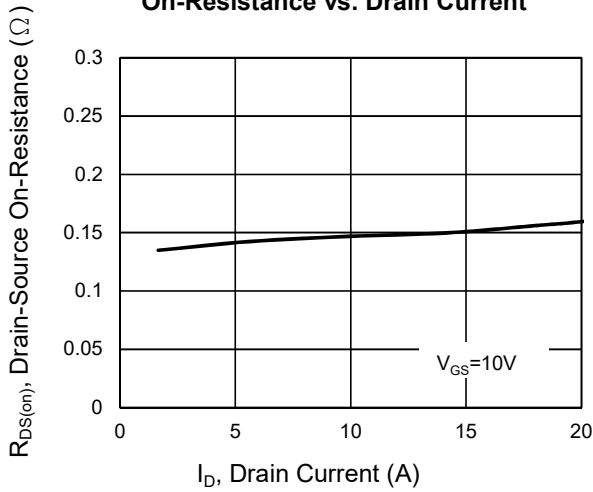
Output Characteristics



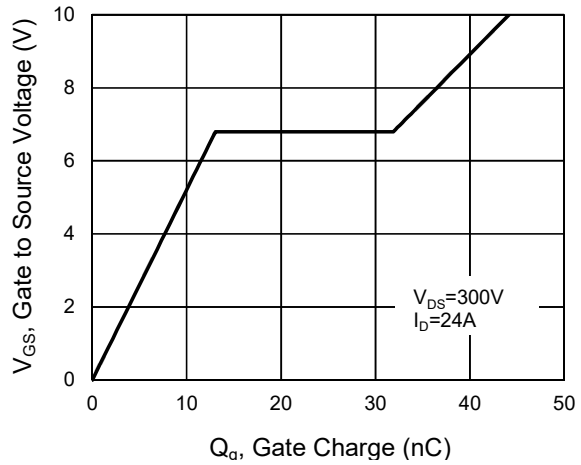
Transfer Characteristics



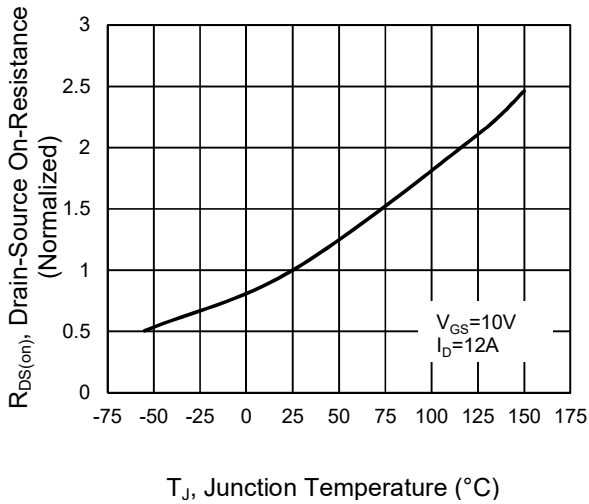
On-Resistance vs. Drain Current



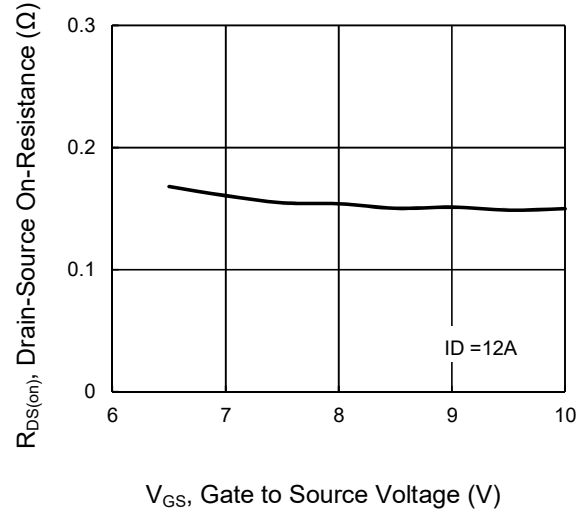
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

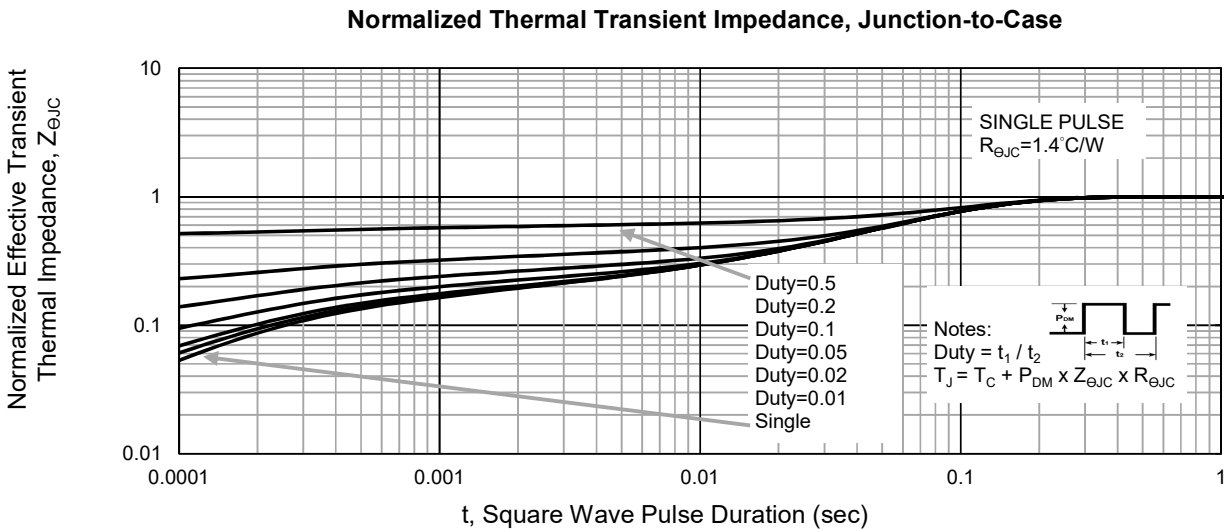
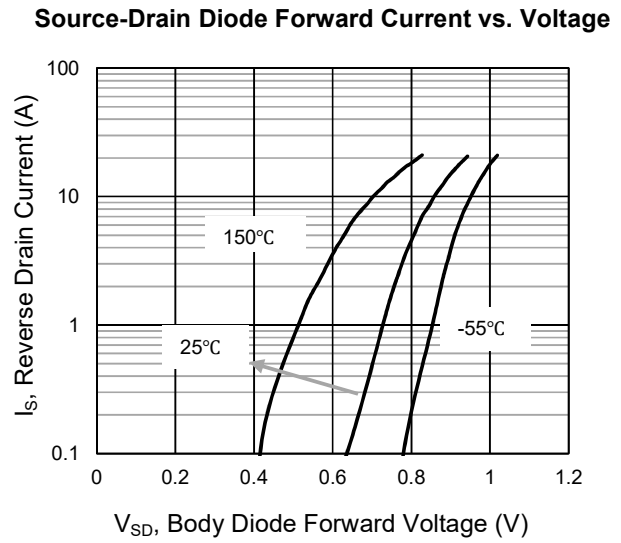
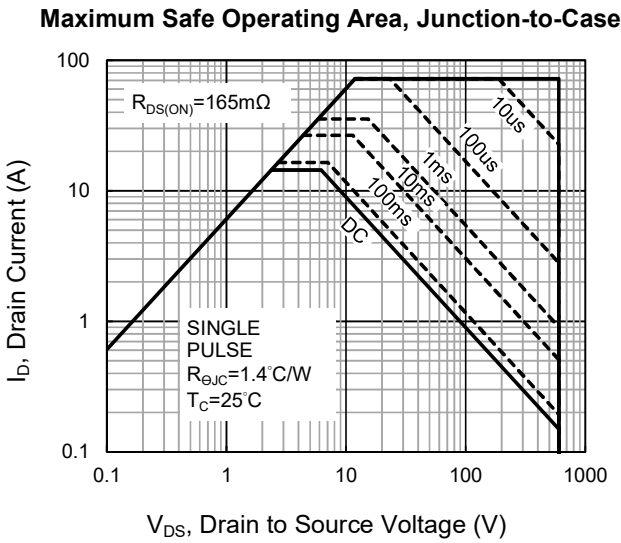
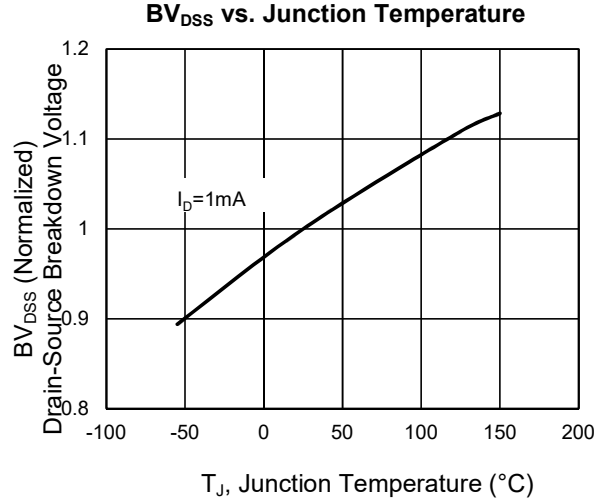
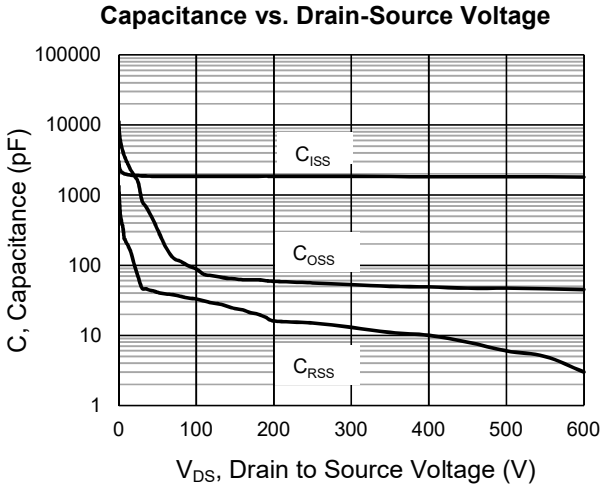


On-Resistance vs. Gate-Source Voltage



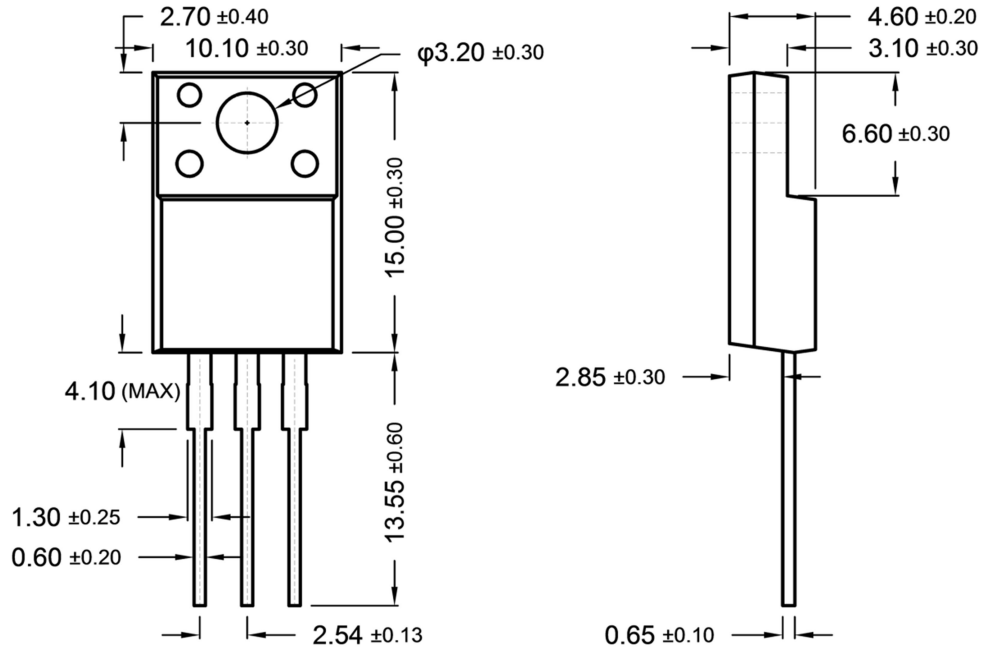
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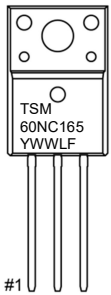


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

ITO-220



MARKING DIAGRAM



- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9,A~Z)
- F** = Factory Code

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